

DESCRIPTION

The 2SC4081X is available in SC-70 package.

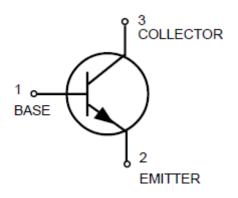
FEATURES

- Low Cob, Cob=2pF(Typ.).
- Epitaxial planar type.
- PNP complement: 2SA1576A
- RoHS Compliant
- Available in SC-70 package

ORDERING INFORMATION

Package Type	Part Number			
SC-70	2SC4081Q			
	2SC4081R			
	2SC4081S			
Note	Note 3,000PCS/Reel			
AiT provides all RoHS Compliant Products				

PIN DESCRIPTION





ABSOLUTE MAXIMUM RATINGS

V _{CEO} , Collector-Emitter Voltage	50V
V _{CBO} , Collector-Base Voltage	60V
V _{EBO} , Emitter-Base Voltage	7.0V
Ic, Collector Current	150mAdc
Pc, Collector Power Dissipation	0.2W
T _j , Junction Temperature	150°C
T _{stg} , Storage Temperature	-55°C ~ +150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE1: P_{C} must not be exceeded

her values are classified as follows:

*	Q	R	S
hef	120~270	180~390	270~560

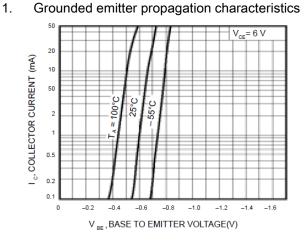


ELECTRICAL CHARACTERISTICS

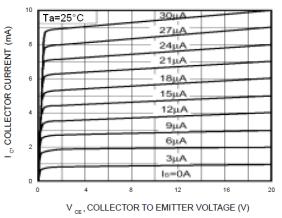
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	V _{(BR)CEO}	Ic = 1mA	50	-	-	V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E = 50μA	7	-	-	V
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = 50μΑ	60	-	-	V
Collector cutoff current	Ісво	V _{CB} = 60V	-	-	0.1	μA
Emitter cutoff current	I _{EBO}	V _{EB} = 7V	-	-	0.1	μA
Collector-emitter saturation voltage	V _{CE(sat)}	Ic/Iв = 50mA /5mA	-	-	0.4	V
DC current transfer ratio	h _{EF}	$V_{CE} = 6V$, $I_C = 1mA$	120	-	560	-
Transition frequency	f⊤	V _{CE} = 12V, I _E = -2mA, f = 30MHz	-	180	-	MHz
Output capacitance	Cob	V _{CB} =12V, I _E =0A, f=1MHz	-	2.0	3.5	pF



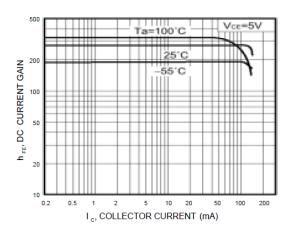
TYPICAL PERFORMANCE CHARACTERISTICS



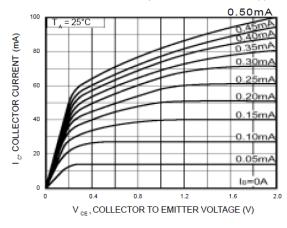
3. Grounded emitter output characteristics(II)



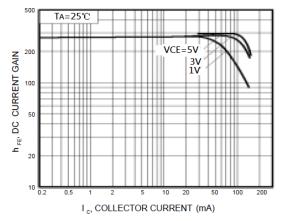
5. DC current gain vs. collector current (II)



2. Grounded emitter output characteristics(I)



4. DC current gain vs. collector current (I)



6. Collector-emitter saturation voltage vs.

SATURATION VOLTAGE(V) 0.2 Ic É IB 50 20 10 0.1 0.05 COLLECTOR 0.02 CE (sat) 0.01 > 0.2 0.5 2 10 20 50 100 200 5 I c, COLLECTOR CURRENT (mA)

collector current



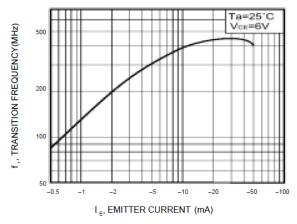
Collector-emitter saturation voltage vs.

collector current (I)

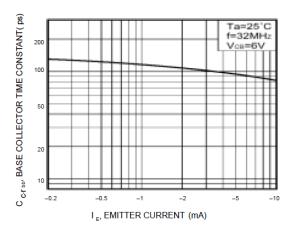
7.

COLLECTOR SATURATION VOLTAGE(V) 0.5 Ic / IB = 10 0.2 Ta=100°C 25°C 0.1 -55°C 0.05 0.02 V _{CE(sat)}, (0.01 0.2 0.5 2 5 10 20 50 100 200 1 I ,, COLLECTOR CURRENT (mA)

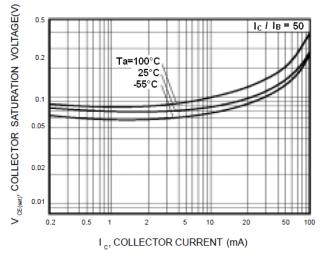
9. Gain bandwidth product vs. emitter current



11. Base-collector time constant vs. emitter current

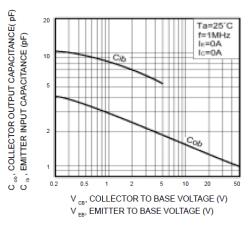


 Collector-emitter saturation voltage vs. collector current (II)



10. Collector output capacitance vs. collector-base voltage

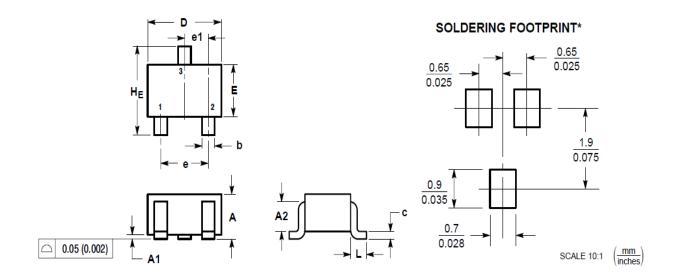
Emitter input capacitance vs. emitter-base voltage





PACKAGE INFORMATION

Dimension in SC-70 Package (Unit: mm)



DIM	MILLIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
А	0.80	1.00	0.032	0.040	
A1	0.00	0.10	0.000	0.004	
A2	0.7 REF		0.028 REF		
b	0.30	0.40	0.012	0.016	
с	0.10	0.25	0.004	0.010	
D	1.80	2.20	0.071	0.087	
E	1.15	1.35	0.045	0.053	
е	1.20	1.40	0.047	0.055	
e1	0.65 BSC		0.026 BSC		
L	0.425 REF		0.017 REF		
HE	2.00	2.40	0.079	0.095	



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